





2.0A SURFACE MOUNT ULTRA-FAST RECTIFIER

Product Summary (@ TA = +25°C)

| V _{RRM} (V) | lo (A) | V _F Max (V) | I _R Max (μA) | Trr (ns) |
|----------------------|--------|------------------------|-------------------------|----------|
| 200 | 2 | 0.92 | 5 | 25 |

Description

The FES2DE is a rectifier packaged in the DO-219AA package and is suited as a boost diode in power factor correction circuitry. This device is for use in secondary rectification and freewheeling for ultrafast switching speed AC-AC and DC-DC converters in high-temperature conditions for consumer applications.

Applications

- Flat Panel Display
- Switching Power Supplies/Chargers
- LED Lighting
- Freewheeling Diode

Features and Benefits

- Low Profile, Small Form Factor Package
- Low Leakage Current
- Glass Passivated Die Construction
- Superfast Recovery Time for High-Efficiency
- Low Forward Voltage, Low Power Loss
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (FES2DEQ)

Mechanical Data

- Case: DO-219AA
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Lead-Frame.
 Solderable per MIL-STD-202, Method 208 @3
- Polarity: Cathode Band
- Weight: 0.016 grams (Approximate)

DO-219AA





Top View

Schematic View

Ordering Information (Note 4)

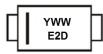
| Part Number | Qualification | Case | Packaging |
|-------------|---------------|----------|------------------|
| FES2DE-7 | Commercial | DO-219AA | 3000/Tape & Reel |

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

DO-219AA



E2D = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 0 = 2020) WW = Week Code(01~53)

Date Code Key

| Date Code Key | | | | | | | | | | | | |
|---------------|------|------|------|------|------|------|------|------|------|------|------|------|
| Year | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 |
| Code | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | 1 |

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Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic | Symbol | Value | Unit |
|---|--------------------------------|-------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | Vrrm V _{RWM} Vr | 200 | ٧ |
| Average Rectified Output Current | lo | 2 | А |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load | IFSM | 50 | А |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|----------|-------------|------|
| Characteristic | Зуньы | value | Onit |
| Typical Thermal Resistance Junction to Case | Rejc | 25 | °C/W |
| Typical Thermal Resistance Junction to Ambient (Note 5) | Reja | 70 | °C/W |
| Typical Thermal Resistance Junction to Lead (Note 5) | Rejl | 20 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)

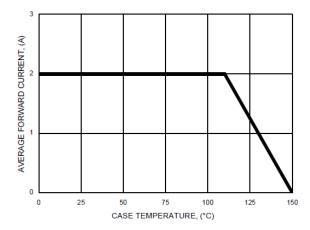
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|------------------------------------|--------------------|-----|-------------|----------|------|---|
| Reverse Breakdown Voltage (Note 6) | V _{(BR)R} | 200 | - | _ | V | I _R = 10μA |
| Forward Voltage | VF | _ | 0.87 | 0.92 | V | I _F = 2A, T _J = +25°C |
| Reverse Leakage Current (Note 6) | IR | | 0.01 1.2 | 5 350 | μΑ | V _R = 200V, T _J = +25°C V _R = 200V, T _J = +125°C |
| Reverse Recovery Time | t _{RR} | _ | _ | 25 | ns | IF = 0.5A, IR = 1.0A, IRR = 0.25A |
| Typical Total Capacitance | Ст | | 32 | | pF | $V_R = 4V$, $f=1MHz$ |

Notes:

- 5. Thermal resistance test performed in accordance with JESD-51.
- 6. Short duration pulse test used to minimize self-heating effect.

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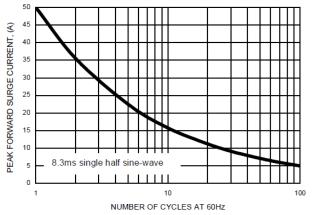


FIG.1- FORWARD CURRENT DERATING CURVE

FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

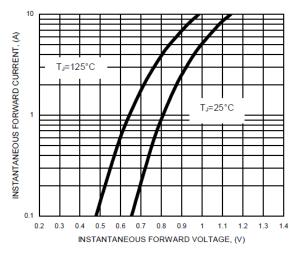


FIG.3-TYPICAL FORWARD CHARACTERISTICS

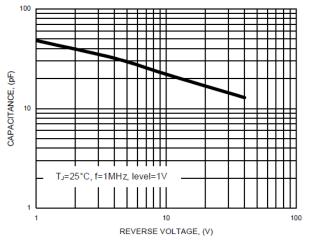


FIG.4-TYPICAL TOTAL CAPACITANCE

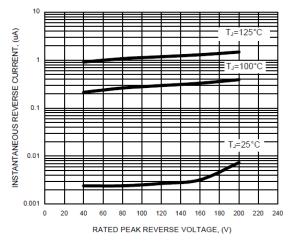


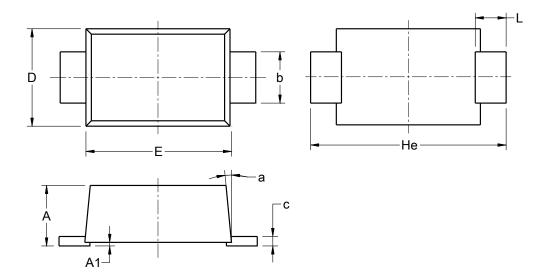
FIG.5- TYPICAL REVERSE CHARACTERISTICS



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

DO-219AA

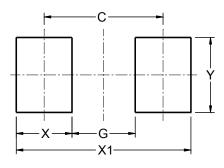


| DO-219AA | | | | | | |
|----------------------|------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.81 | 1.20 | 1.18 | | | |
| A1 | 0.03 | 0.10 | 0.07 | | | |
| b | 0.85 | 1.15 | 1.00 | | | |
| С | 0.05 | 0.30 | 0.15 | | | |
| D | 1.70 | 2.00 | 1.90 | | | |
| Е | 2.70 | 2.90 | 2.80 | | | |
| Не | 3.50 | 3.90 | 3.80 | | | |
| L | 0.45 | 0.75 | 0.60 | | | |
| а | 0° | 8° | 5° | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

DO-219AA



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 2.86 |
| G | 1.52 |
| Х | 1.34 |
| X1 | 4.20 |
| Υ | 1.80 |



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